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L. Spruell

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of
Zhijun Qu and Kenneth Wagers

New York, New York

Date: May 15, 2000

Serial No.: 09/329,156

Group Art Unit: 2811

Filed: June 9, 1999

Examiner: S. Hu

For: DUAL EPITAXIAL LAYER FOR HIGH VOLTAGE VERTICAL
CONDUCTION POWER MOSFET DEVICES

Assistant Commissioner for Patents
Washington, D.C. 20231

INFORMATION DISCLOSURE STATEMENT

Sir:

Submitted herewith is a copy of art together with a form listing the same
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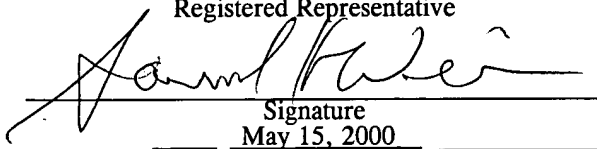
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Respectfully submitted,

Samuel H. Weiner

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Signature

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